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December 2001

FDN306P

AIRCHILD SEMICONDUCTOR

P-Channel 1.8V Specified PowerTrench[®] MOSFET

General Description

This P-Channel 1.8V specified MOSFET uses Fairchild's advanced low voltage PowerTrench process. It has been optimized for battery power management applications.

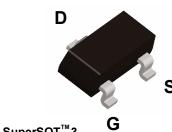
Applications

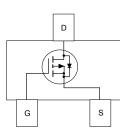
- Battery management
- · Load switch
- Battery protection

Features

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• -2.6 A, -12 V. R_{DS(ON)} = 40 m\Omega @ V<sub>GS</sub> = -4.5 V
                 R_{DS(ON)} = 50 \text{ m}\Omega @ V_{GS} = -2.5 \text{ V}
                 R_{DS(ON)} = 80 m\Omega @ V<sub>GS</sub> = -1.8 V
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- Fast switching speed
- High performance trench technology for extremely low R_{DS(ON)}
- $SuperSOT^{\text{TM}}$ -3 provides low $R_{\text{DS}(\text{ON})}$ and 30% higher power handling capability than SOT23 in the same footprint





SuperSOT[™]-3

Absolute Maximum Ratings TA=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-Source Voltage		-12	V
V _{GSS}	Gate-Source Voltage		±8	V
I _D	Drain Current – Continuous	(Note 1a)	-2.6	A
	– Pulsed		-10	
P _D	Maximum Power Dissipation	(Note 1a)	0.5	W
		(Note 1b)	0.46	
T_{J}, T_{STG}	Operating and Storage Junction Temperatu	ure Range	-55 to +150	°C
Therma	I Characteristics			
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	250	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	(Note 1)	75	°C/W

Package Marking and Ordering Information

 Device Marking	Device	Reel Size	Tape width	Quantity
306	FDN306P	7"	8mm	3000 units

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FDN306P

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V$, $I_D = -250 \mu A$	-12			V
<u>ΔBV_{DSS}</u> ΔT _J	Breakdown Voltage Temperature Coefficient	I_D = -250 µA,Referenced to 25°C		-3		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -10 V$, $V_{GS} = 0 V$			-1	μA
I _{GSSF}	Gate-Body Leakage, Forward	V _{GS} = 8 V, V _{DS} = 0 V			100	nA
I _{GSSR}	Gate-Body Leakage, Reverse	$V_{GS} = -8 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$	-0.4	-0.6	-1.5	V
<u>ΔVGS(th)</u> ΔTJ	Gate Threshold Voltage Temperature Coefficient	I_D = –250 µA,Referenced to 25°C		2.5		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$ \begin{array}{l} V_{GS} = -4.5 \ V, I_D = -2.6 \ A \\ V_{GS} = -2.5 \ V, I_D = -2.3 \ A \\ V_{GS} = -1.8 \ V, I_D = -1.8 \ A \\ V_{GS} = -4.5 \ V, \ I_D = -2.6 \ A, \ T_J = 125^\circ C \end{array} $		30 39 54 40	40 50 80 54	mΩ
I _{D(on)}	On-State Drain Current	$V_{GS} = -4.5 V$, $V_{DS} = -5 V$	-10			Α
g _{FS}	Forward Transconductance	$V_{DS} = -5 V$, $I_D = -2.6 A$		10		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = -6 V$, $V_{GS} = 0 V$,		1138		pF
Coss	Output Capacitance	f = 1.0 MHz		454		pF
C _{rss}	Reverse Transfer Capacitance			302		pF
Switchin	ng Characteristics (Note 2)					
t _{d(on)}	Turn–On Delay Time	$V_{DD} = -6 V$, $I_D = -1 A$, $V_{GS} = -4.5 V$, $R_{GEN} = 6 \Omega$		11	20	ns
tr	Turn–On Rise Time	V_{GS} = -4.5 V, R_{GEN} = 6 Ω		10	20	ns
t _{d(off)}	Turn–Off Delay Time			38	61	ns
t _f	Turn–Off Fall Time			35	56	ns
Qg	Total Gate Charge	$V_{DS} = -6 V$, $I_D = -2.6 A$,		12	17	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = -4.5 V$		2		nC
Q _{gd}	Gate–Drain Charge			3		nC
Drain-S	ource Diode Characteristics	and Maximum Ratings				
ls	Maximum Continuous Drain-Sourc	Ŭ			-0.42	Α
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_S = -0.42$ (Note 2)		-0.6	-1.2	V

 R_{8JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{8JC} is guaranteed by design while R_{8CA} is determined by the user's board design.

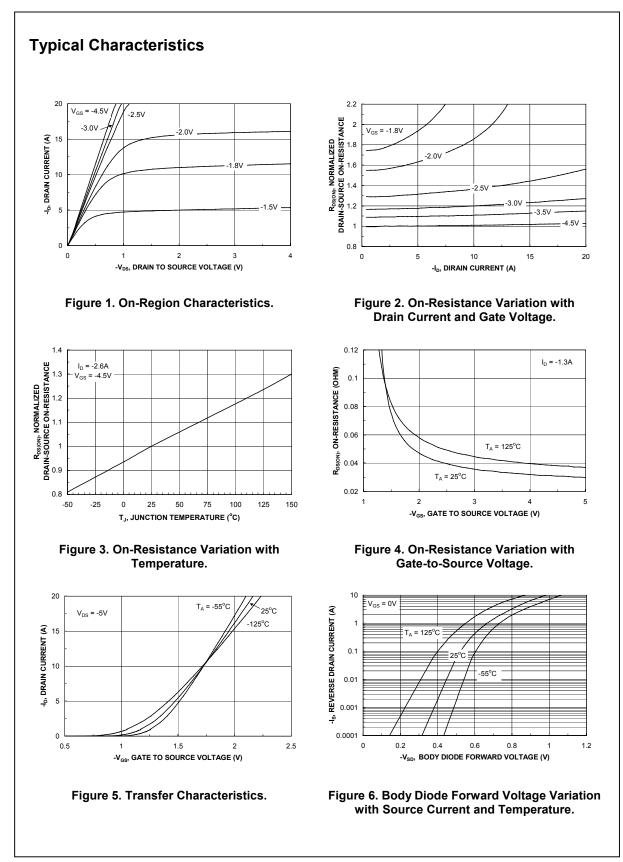
a) 250°C/W when mounted on a 0.02 in² pad of 2 oz. copper.

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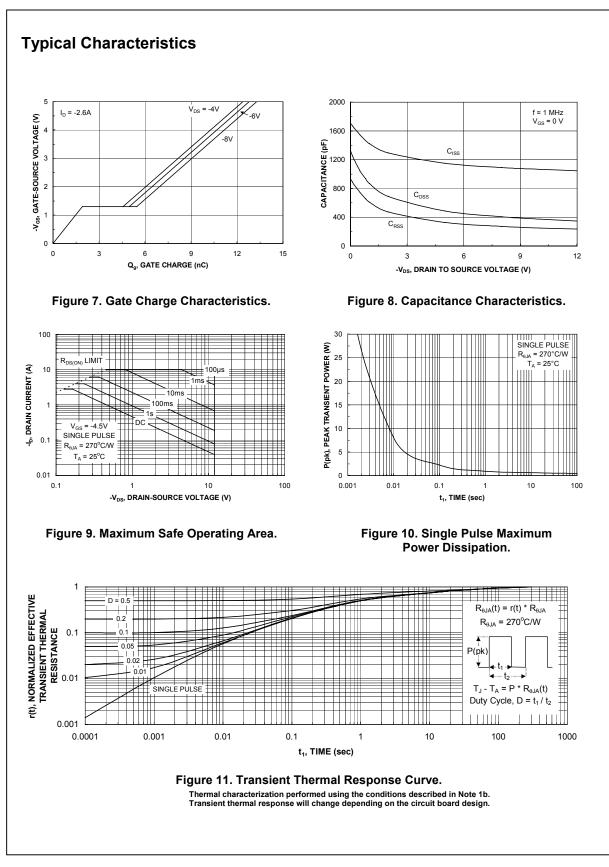
b) 270°C/W when mounted on a minimum pad.

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width $\leq 300~\mu s,~Duty~Cycle \leq 2.0\%$



FDN306P



FDN306P

FDN306P Rev D W)

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